

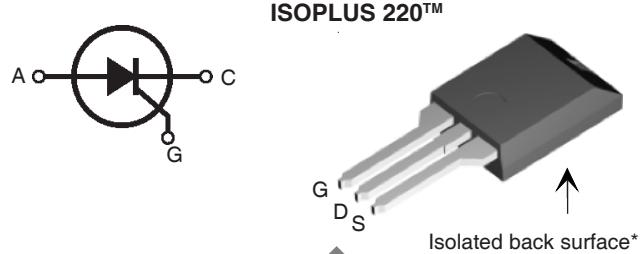
Phase Control Thyristor

ISOPLUS220™

Electrically Isolated Back Surface

V_{RRM} = 800 - 1200 V
 $I_{T(RMS)}$ = 35 A
 $I_{T(AV)M}$ = 13 A

V_{RSM}	V_{RRM}	Type
V_{DSM}	V_{DRM}	
V	V	
800	800	CS 19-08ho1C
1200	1200	CS 19-12ho1C



Symbol	Test Conditions	Maximum Ratings	
$I_{T(RMS)}$	$T_{VJ} = T_{VJM}$	35	A
$I_{T(AV)M}$	$T_C = 85^\circ\text{C}$; 180° sine	13	A
I_{TSM}	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0 \text{ V}$ $t = 8.3 \text{ ms}$ (60 Hz), sine	100	A
	$T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0 \text{ V}$ $t = 8.3 \text{ ms}$ (60 Hz), sine	105	A
I^2t	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0 \text{ V}$ $t = 8.3 \text{ ms}$ (60 Hz), sine	85	A
	$T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0 \text{ V}$ $t = 8.3 \text{ ms}$ (60 Hz), sine	90	A
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ repetitive, $I_T = 20 \text{ A}$ $f = 50 \text{ Hz}$, $t_p = 200 \mu\text{s}$ $V_D = 2/3 V_{DRM}$ $I_G = 0.08 \text{ A}$ non repetitive, $I_T = I_{T(AV)M}$ $di_G/dt = 0.08 \text{ A}/\mu\text{s}$	50	A^2s
		45	A^2s
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$; $V_{DR} = 2/3 V_{DRM}$ $R_{GK} = \infty$; method 1 (linear voltage rise)	100	$\text{A}/\mu\text{s}$
P_{GM}	$T_{VJ} = T_{VJM}$ $t_p = 30 \mu\text{s}$ $I_T = I_{T(AV)M}$ $t_p = 300 \mu\text{s}$	500	$\text{V}/\mu\text{s}$
P_{GAV}		2.5	W
V_{RGM}		0.5	W
T_{VJ}		10	V
T_{VJM}		-40...+125	$^\circ\text{C}$
T_{stg}		125	$^\circ\text{C}$
V_{ISOL}	50/60 Hz RMS; $I_{ISOL} \leq 1 \text{ mA}$	-40...+125	$^\circ\text{C}$
T_L	1.6mm from case; 10s	2500	V_\sim
F_c	Mounting force	260	$^\circ\text{C}$
Weight		11...65 / 2.4...11	N / lb
		2	g

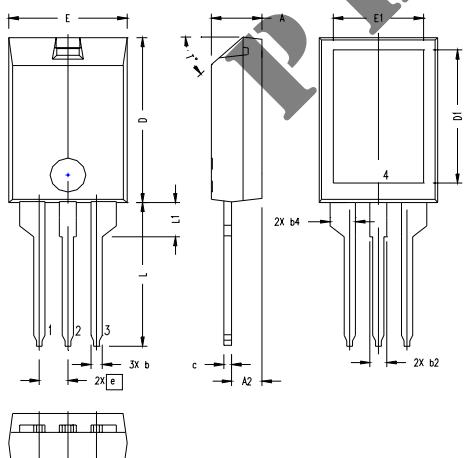
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DS98789A(8/03)

Symbol	Test Conditions	Characteristic Values		
I_R, I_D	$T_{VJ} = T_{VJM}$; $V_R = V_{RRM}$; $V_D = V_{DRM}$	≤	1	mA
V_T	$I_T = 30 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$	≤	1.65	V
V_{T0}	For power-loss calculations only ($T_{VJ} = 125^\circ\text{C}$)	0.87	V	
r_T		29	$\text{m}\Omega$	
V_{GT}	$V_D = 6 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	≤	1.5	V
I_{GT}	$V_D = 6 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$	≤	25	mA
V_{GD}	$T_{VJ} = T_{VJM}$; $V_D = 2/3 V_{DRM}$	≤	0.2	V
I_{GD}		≤	3	mA
I_L	$T_{VJ} = 25^\circ\text{C}$; $t_p = 10 \mu\text{s}$ $I_G = 0.08 \text{ A}$; $di_G/dt = 0.08 \text{ A}/\mu\text{s}$	≤	75	mA
I_H	$T_{VJ} = 25^\circ\text{C}$; $V_D = 6 \text{ V}$; $R_{GK} = \infty$	≤	50	mA
t_{gd}	$T_{VJ} = 25^\circ\text{C}$; $V_D = 1/2 V_{DRM}$ $I_G = 0.08 \text{ A}$; $di_G/dt = 0.08 \text{ A}/\mu\text{s}$	≤	2	μs
R_{thJC}	DC current	typical		
R_{thCK}	DC current	1.7	K/W	
a	Max. acceleration, 50 Hz	0.6	K/W	
		50	m/s^2	

ISOPLUS220 OUTLINE



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.157	.197	4.00	5.00
A2	.098	.118	2.50	3.00
b	.035	.051	0.90	1.30
b2	.049	.065	1.25	1.65
b4	.093	.100	2.35	2.55
c	.028	.039	0.70	1.00
D	.591	.630	15.00	16.00
D1	.472	.512	12.00	13.00
E	.394	.433	10.00	11.00
E1	.295	.335	7.50	8.50
e	.100	BASIC	2.55	BASIC
L	.512	.571	13.00	14.50
L1	.118	.138	3.00	3.50
T*			42.5°	47.5°

NOTE:

- Bottom heatsink (Pin 4) is electrically isolated from Pin 1, 2, or 3.
- This drawing will meet dimensional requirement of JEDEC SS Product Outline TO-273 except D and D1 dimension.